

# Isc N-Channel MOSFET Transistor

# IPA65R660CFD

### • FEATURES

- With TO-220F Package
- Drain Source Voltage  
:  $V_{DSS}=650V(\text{Min})$
- Static Drain-Source On-Resistance  
:  $R_{DS(on)} = 0.66 \Omega (\text{Max})$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### • APPLICATIONS

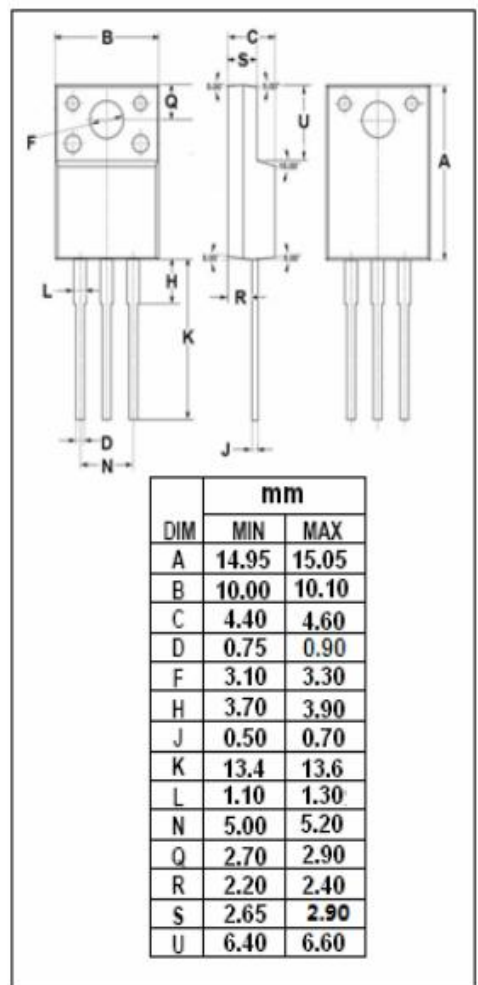
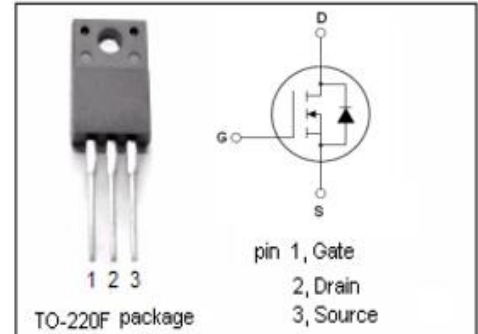
- Switching applications

### • ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	650	V
$V_{GSS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous @ $T_c=25^\circ\text{C}$ ( $V_{GS}$ at 10V) $T_c=100^\circ\text{C}$	6 3.8	A
$I_{DM}$	Drain Current-Single Pulsed	17	A
$P_D$	Total Dissipation @ $T_c=25^\circ\text{C}$	28	W
$T_j$	Max. Operating Junction Temperature	-55~150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~150	$^\circ\text{C}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	4.5	$^\circ\text{C}/\text{W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	80	$^\circ\text{C}/\text{W}$



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## • ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =1mA	650			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =0.21mA	3.5	4	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =2.1A		0.59	0.66	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V; V <sub>DS</sub> = 0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V; T <sub>j</sub> =25°C V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V; T <sub>j</sub> =150°C		600	5	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> = 3.2A, V <sub>GS</sub> = 0 V		0.9		V

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